



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

## Digital transistors (built-in resistors)

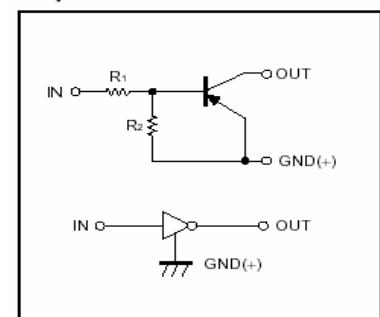
### DTA143ZE/ DTA143ZUA/ DTA143ZCA/DTA143ZKA/DTA143ZSA

DIGITAL TRANSISTOR (PNP)

#### Features

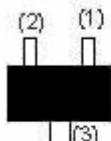
- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

#### ● Equivalent circuit



#### PIN CONNECTIONS AND MARKING

DTA143ZE

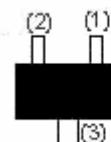


1.IN  
2.GND  
3.OUT

SOT-523

Addreviated symbol: E13

DTA143ZUA

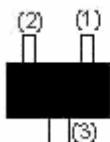


1.IN  
2.GND  
3.OUT

SOT-323

Addreviated symbol: 113

DTA143ZKA

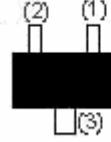


1.IN  
2.GND  
3.OUT

SOT-23-3L

Addreviated symbol: E13

DTA143ZCA

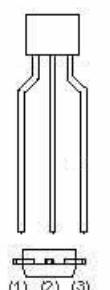


1.IN  
2.GND  
3.OUT

SOT-23

Addreviated symbol: E13

DTA143ZSA



1.GND  
2.OUT  
3.IN

TO-92S

## Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA143Z□ )					Unit
		E	UA	KA	CA	SA	
Supply voltage	V <sub>CC</sub>			-50			V
Input voltage	V <sub>IN</sub>			-30~5			V
Output current	I <sub>O</sub>			-100			mA
	I <sub>C(MAX)</sub>			-100			
Power dissipation	P <sub>d</sub>	150		200		300	mW
Junction temperature	T <sub>j</sub>			150			°C
Storage temperature	T <sub>stg</sub>			-55~150			°C

## Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>			-0.5	V	V <sub>CC</sub> =-5V ,I <sub>O</sub> =-100μA
	V <sub>I(on)</sub>	-1.3				V <sub>O</sub> =-0.3V ,I <sub>O</sub> =-5 mA
Output voltage	V <sub>O(on)</sub>			-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-5mA/-0.25mA
Input current	I <sub>I</sub>			-1.8	mA	V <sub>I</sub> =-5V
Output current	I <sub>O(off)</sub>			-0.5	μA	V <sub>CC</sub> =-50V ,V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	80				V <sub>O</sub> =-5V ,I <sub>O</sub> =-10mA
Input resistance	R <sub>I</sub>	3.29	4.7	6.11	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	8	10	12		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =-10V ,I <sub>O</sub> =-5mA,f=100MHz

## Typical Characteristics

### ●Electrical characteristic curves

